



FZT690B

45V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

Features

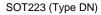
- $BV_{CEO} > 45V$
- $BV_{CBO} > 45V$
- I_C = 3.0A High Continuous Current
- hFE > 400 @ 1A and Low Saturation Voltage
- $R_{CE(SAT)} = 125m\Omega$ @ 2A for Low Equivalent On-Resistance
- Very Low-Saturation Voltage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

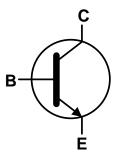
Applications

- **Darlington Replacement**
- Flash-Gun Convertors and Battery-Powered Circuits
- Siren Drivers, DC-DC Converters

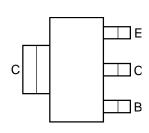




Top View



Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 and 5)

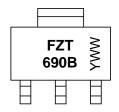
Ī	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
I	FZT690BTA	AEC-Q101	FZT690B	7	12	1,000
ľ	FZT690BQTA	Automotive	FZT690B	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223 (Type DN)



FZT690B = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 8= 2018) WW or $\overline{W}W = Week Code (01 to 53)$



Absolute Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	45	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	3	Α
Peak Pulse Current	I _{CM}	6	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)	P _D	3.0		
Dower Dissipation	(Note 7)		2.0	W	
Power Dissipation	(Note 8)		1.6		
	(Note 9)		1.2		
	(Note 6)	R _{θJA}	41.7		
Thermal Resistance, Junction to Ambient	(Note 7)		62.5		
Thermal Resistance, Junction to Ambient	(Note 8)		78.1	°C/W	
	(Note 9)		104		
Thermal Resistance Junction to Lead (Note		$R_{ hetaJL}$	12.9		
Operating and Storage Temperature Range	T_{J} , T_{STG}	-55 to +150	°C		

ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

- 6. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

- 7. Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.

 8. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

 9. Same as Note 6, except the device is mounted on minimum recommended pad layout.

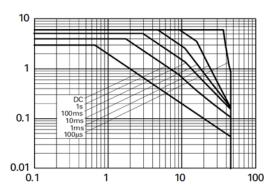
 10. Thermal resistance from junction to solder-point (at the end of the collector lead).

 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

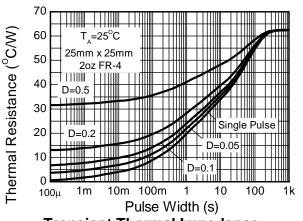


Thermal Characteristics and Derating Information

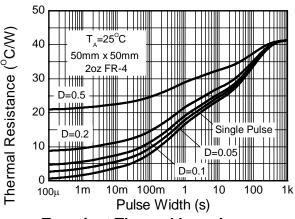
Ic-Collector Current (A)



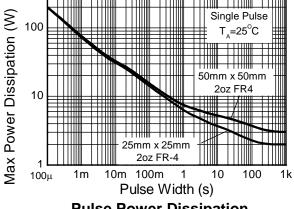
VŒ - Collector Emitter Voltage (V) Safe Operating Area



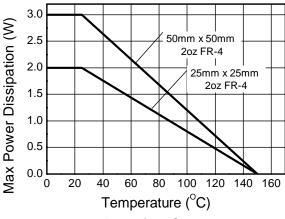
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve



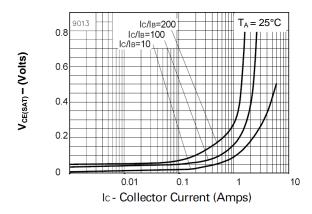
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	45	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 12)	BV _{CEO}	45	_	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	I _E = 100μA
Collector-Base Cut-Off Current	I _{CBO}	_	_	0.1	μA	V _{CB} = 35V
Emitter Cut-Off Current	I _{EBO}	1	_	0.1	μA	V _{EB} = 4V
DC Current Gain (Note 12)	h _{FE}	500 400 150 50		111	_	$I_{C} = 0.1A, V_{CE} = 2V$ $I_{C} = 1A, V_{CE} = 2V$ $I_{C} = 2A, V_{CE} = 2V$ $I_{C} = 3A, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 12)	V _{CE(SAT)}		_	0.10 0.50	V	$I_C = 0.1A, I_B = 0.5mA$ $I_C = 1A, I_B = 5mA$
Base-Emitter Saturation Voltage (Note 12)	V _{BE(SAT)}	_	_	0.9	V	I _C = 1A, I _B = 10mA
Base-Emitter Turn-On Voltage (Note 12)	V _{BE(ON)}	_	_	0.9	V	I _C = 1A, V _{CE} = 2V
Input Capacitance	C _{ibo}	_	200	_	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	C _{obo}	_	16	_	pF	V _{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product	f _T	150	_	_	MHz	$V_{CE} = 5V$, $I_C = 50$ mA, $f=50$ MHz
Turn-On Time	t _{ON}		33		ns	V _{CC} = 10V, I _C = 500mA
Turn-Off Time	toff	_	1,300	_	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$

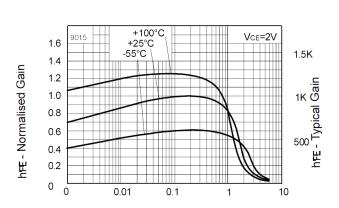
Note: 12. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

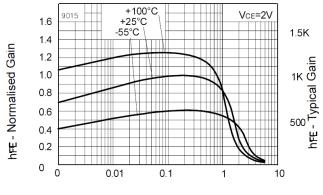






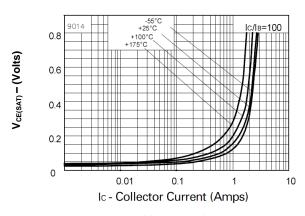
Ic - Collector Current (Amps)

hFE v IC

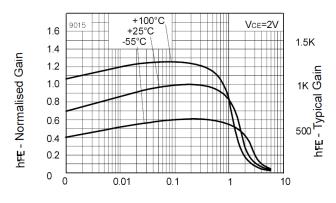


Ic - Collector Current (Amps)

hFE v IC



 $V_{CE(SAT)} v I_C$



Ic - Collector Current (Amps)

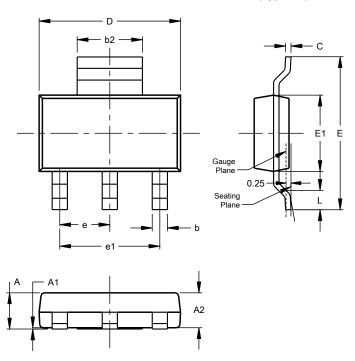
hFE v IC



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

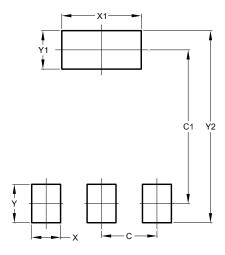


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
C	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)				
С	2.30				
C1	6.40				
Х	1.20				
X1	3.30				
Υ	1.60				
Y1	1.60				
Y2	8.00				



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